



MT SERIES

THREE PHASE BRIDGE

Power Modules

Features

- Universal, 3 way terminals:
push-on, wrap around or solder
- High thermal conductivity package,
electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- UL E 62320 approved
- Terminals Solderable as per MIL-STD-202 METHOD 208,
solder: Sn/Pb (60/40); solder temperature: 235-260°C mx. time: 8-10 sec.

25 A
35 A

Description

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

Major Ratings and Characteristics

Parameters	26MT	36MT	Units
I_o	25	35	A
@ T_c	70	60	°C
I_{FSM}	@ 50Hz	360	A
	@ 60Hz	375	A
I^2t	@ 50Hz	635	A^2s
	@ 60Hz	580	A^2s
V_{RRM} range	100 to 1600		V
T_j	-55 to 150		°C

26MT../36MT.. Series

Bulletin I2771 rev. E 04/03

International
Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ T_j max. mA
26MT.. / 36MT..	10	100	150	2
	20	200	275	
	40	400	500	
	60	600	725	
	80	800	900	
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	
	160	1600	1700	

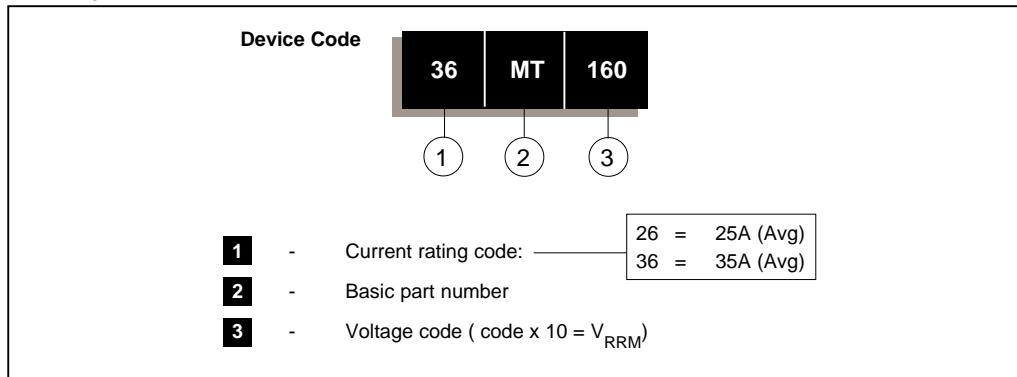
Forward Conduction

Parameters		26MT	36MT	Units	Conditions					
I_o	Maximum DC output current @ T_c	25	35	A	120° Rect Conduction angle					
		70	60	°C						
I_{FSM}	Maximum peak, one-cycle non-repetitive forward current	360	475	A	$t=10ms$	No voltage reapplied	Initial $T_j = T_{j\max}$			
		375	500		$t=8.3ms$					
	Initial $T_j = T_{j\max}$.	300	400		$t=10ms$	100% V_{RRM} reapplied				
		314	420		$t=8.3ms$	reapplied				
I^2t	Maximum I^2t for fusing	635	1130	A ² s	$t=10ms$	No voltage reapplied	Initial $T_j = T_{j\max}$			
	Initial $T_j = T_{j\max}$.	580	1030		$t=8.3ms$					
		450	800		$t=10ms$	100% V_{RRM} reapplied				
		410	730		$t=8.3ms$					
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	6360	11300	A ² /s	$I^2\sqrt{t} = I^2\sqrt{t_x} \cdot t_x ; 0.1 \leq t_x \leq 10ms, V_{RRM} = 0V$					
$V_{F(TO)1}$	Low-level of threshold voltage	0.88	0.86	V	(16.7% $\times \pi \times I_{F(AV)}$ < $ I < \pi \times I_{F(AV)}$), @ T_j max.					
$V_{F(TO)2}$	High-level of threshold voltage	1.13	1.03		$(I > \pi \times I_{F(AV)})$, @ T_j max.					
r_{t1}	Low-level forward slope resistance	7.9	6.3	mΩ	(16.7% $\times \pi \times I_{F(AV)}$ < $ I < \pi \times I_{F(AV)}$), @ T_j max.					
r_{t2}	High-level forward slope resistance	5.2	5.0		$(I > \pi \times I_{F(AV)})$, @ T_j max.					
V_{FM}	Maximum forward voltage drop	1.26	1.19	V	$T_j = 25^\circ C, I_{FM} = 40A_{pk}$ - Per single Junction					
I_{RRM}	Max. DC reverse current	100		μA	$T_j = 25^\circ C$, per Junction at rated V_{RRM}					
V_{INS}	RMS isolation voltage	2700		V	$T_j = 25^\circ C$, All terminal shorted $f = 50Hz, t = 1s$					

Thermal and Mechanical Specifications

Parameters	26MT	36MT	Units	Conditions
T_J Max. junction temperature range	-55 to 150	°C		
T_{stg} Max. storage temperature range	-55 to 150	°C		
R_{thJC} Max. thermal resistance junction to case	1.42	1.35	K/W	DC operation per bridge (Based on total power loss of bridge)
R_{thCS} Max. thermal resistance, case to heatsink	0.2	0.2	K/W	Mounting surface, smooth, flat and greased
wt Approximate weight	20	g		
T Mounting Torque $\pm 10\%$	2.0	Nm		Bridge to heatsink with screw M4

Ordering Information Table



Outline Table

